

# **Device Modeling Report**

COMPONENTS:  
DIODE/ SCHOTTKY RECTIFIER / STANDARD  
PART NUMBER: EA30QS03L-F  
MANUFACTURER: NIEC

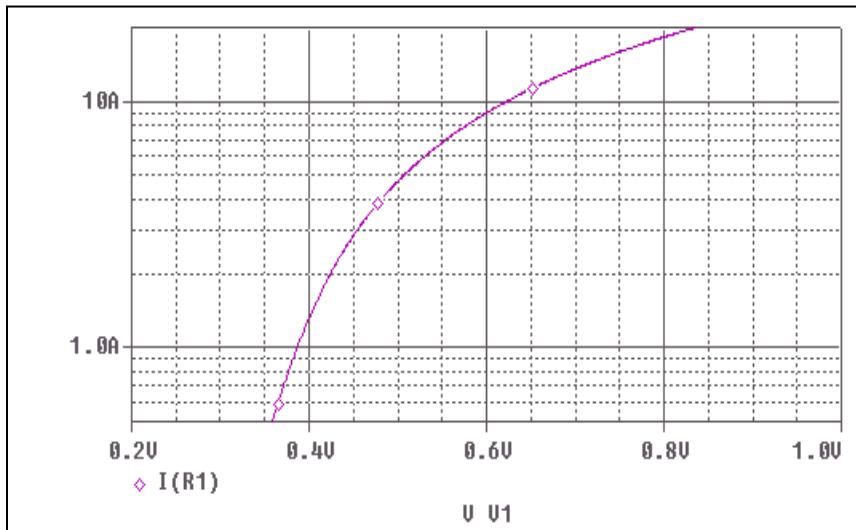


**Bee Technologies Inc.**

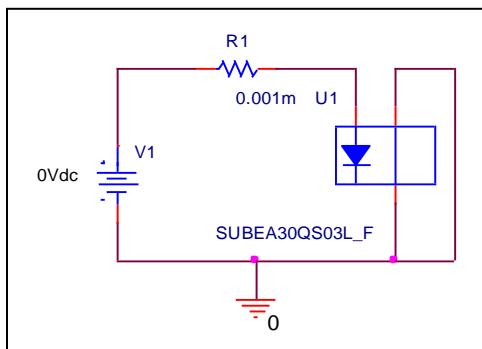
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

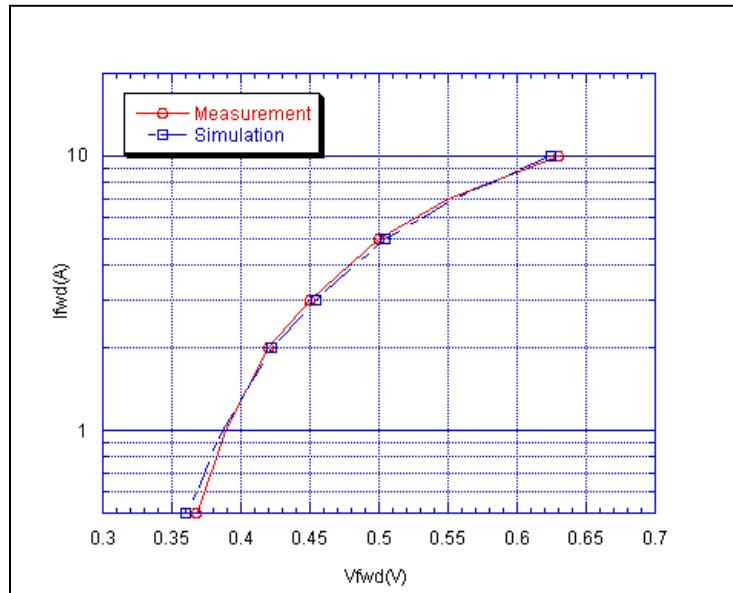


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result

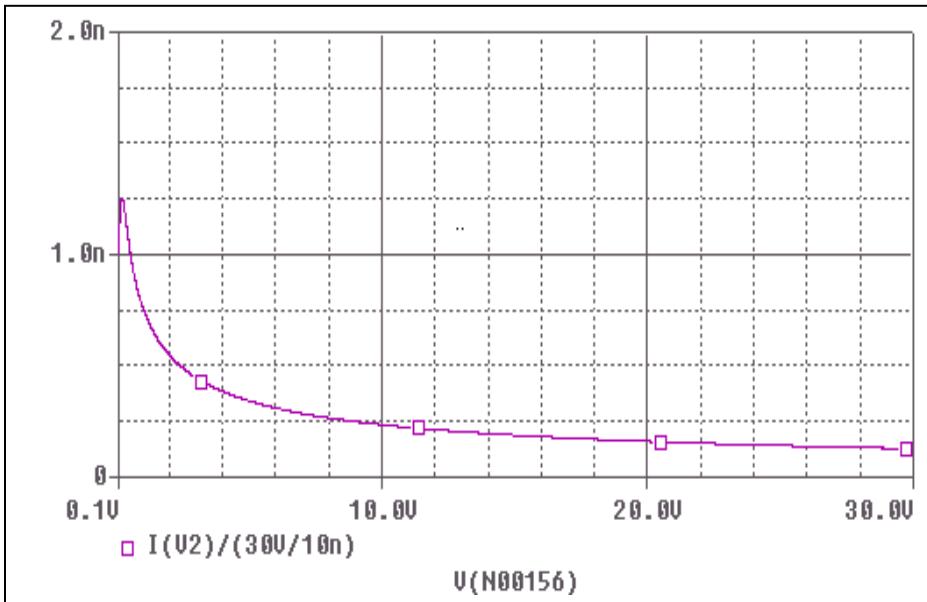


### Simulation Result

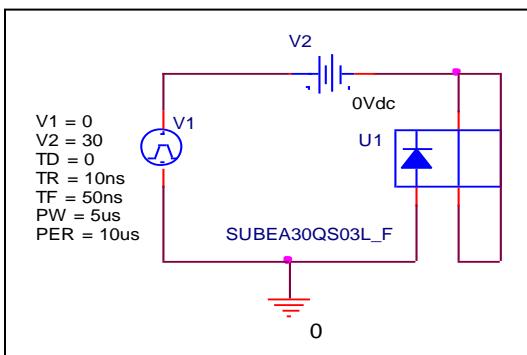
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.5	0.368	0.360	-2.17
1	0.389	0.387	-0.51
2	0.420	0.422	0.48
5	0.500	0.505	1.00
10	0.630	0.625	-0.79

## Capacitance Characteristic

### Circuit Simulation Result

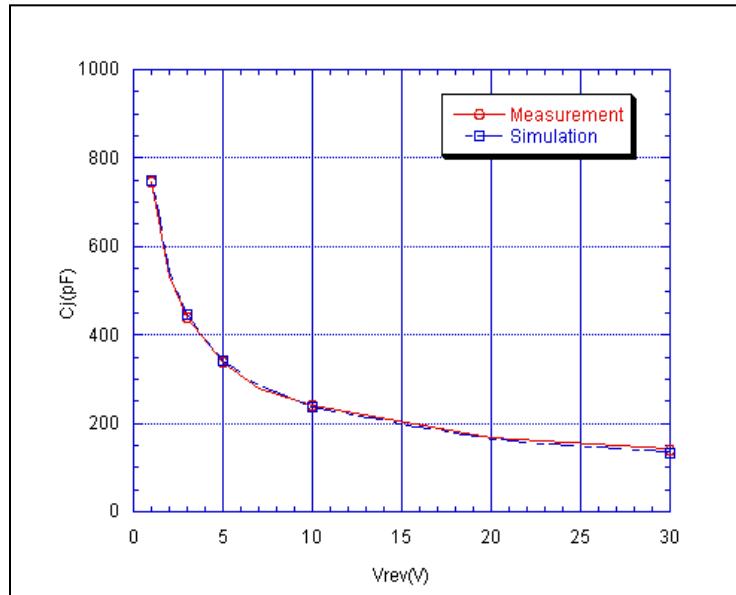


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result



Simulation Result

$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
1	745.000	751.000	0.81
2	532.000	545.000	2.44
5	338.000	343.000	1.48
10	240.000	238.000	-0.83
20	168.000	165.000	-1.79
30	138.000	133.000	-3.62